

ZUMT591TC Datasheet



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DiGi Electronics Part Number	ZUMT591TC-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	ZUMT591TC
Description	TRANS PNP 60V 1A SOT323
Detailed Description	Bipolar (BJT) Transistor PNP 60 V 1 A 150MHz 500 mW Surface Mount SOT-323



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Purchase and inquiry

Manufacturer Product Number:

ZUMT591TC

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

60 V

Current - Collector Cutoff (Max):

100nA

Power - Max:

500 mW

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

SC-70, SOT-323

Base Product Number:

ZUMT591

Manufacturer:

Diodes Incorporated

Product Status:

Obsolete

Current - Collector (Ic) (Max):

1 A

Vce Saturation (Max) @ Ib, Ic:

600mV @ 100mA, 1A

DC Current Gain (hFE) (Min) @ Ic, Vce:

100 @ 500mA, 5V

Frequency - Transition:

150MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-323

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.21.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

SOT323 PNP SILICON PLANAR HIGH PERFORMANCE TRANSISTOR

DRAFT SPECIFICATION ISSUE A – OCTOBER 94

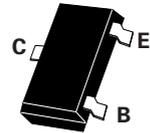
ZUMT591

FEATURES

- * Extremely low saturation voltage
- * 500mW power dissipation
- * 1 Amp continuous collector current (I_C)

APPLICATIONS

- * Ideally suited for space / weight critical applications



SOT323

ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V_{CBO}	-80	V
Collector-Emitter Voltage	V_{CEO}	-60	V
Emitter-Base Voltage	V_{EBO}	-5	V
Peak Pulse Current	I_{CM}	-2	A
Continuous Collector Current	I_C	-1	A
Base Current	I_B	-200	mA
Power Dissipation at $T_{amb}=25^\circ\text{C}$	P_{tot}	500	mW
Operating and Storage Temperature Range	$T_j; T_{stg}$	-55 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ\text{C}$).

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-80			V	$I_C = -100\mu\text{A}$, $I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{CEO(sus)}$	-60			V	$I_C = -10\text{mA}^*$, $I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5			V	$I_E = -100\mu\text{A}$, $I_C = 0$
Collector Cut-Off Current	I_{CBO}			-100	nA	$V_{CB} = -60\text{V}$
Collector Cut-Off Current	I_{CES}			-100	nA	$V_{CE} = -60\text{V}$
Emitter Cut-Off Current	I_{EBO}			-100	nA	$V_{EB} = -4\text{V}$, $I_C = 0$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$			-0.3 -0.6	V	$I_C = -500\text{mA}$, $I_B = -50\text{mA}^*$ $I_C = -1\text{A}$, $I_B = -100\text{mA}^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$			-1.2	V	$I_C = -1\text{A}$, $I_B = -100\text{mA}^*$
Base-Emitter Turn On Voltage	$V_{BE(on)}$			-1.0	V	$I_C = -1\text{A}$, $V_{CE} = -5\text{V}^*$

* Measured under pulsed conditions. Pulse width=300 μs . Duty cycle@2%

ZUMT591

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$).

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Static Forward Current Transfer Ratio	h_{FE}	100 100 80 15		300		$I_C = -1mA, V_{CE} = -5V^*$ $I_C = -500mA, V_{CE} = -5V^*$ $I_C = -1A, V_{CE} = -5V^*$ $I_C = -2A, V_{CE} = -5V^*$
Transition Frequency	f_T	150			MHz	$I_C = -50mA, V_{CE} = -10V^*$ $f = 100MHz$
Output Capacitance	C_{obo}			10	pF	$V_{CB} = -10V, f = 1MHz$

* Measured under pulsed conditions. Pulse width=300 μ s. Duty cycle@2%

NOTE

This data is derived from development material and does not necessarily mean that the device will go into production

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